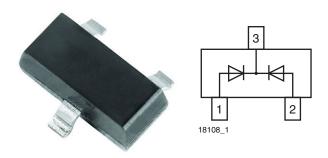
BAV23C

www.vishay.com

Vishay Semiconductors

Small Signal Switching Diode, Dual



DESIGN SUPPORT TOOLS click logo to get started



MECHANICAL DATA

Case: SOT-23 Weight: approx. 8.8 mg Packaging codes / options: 18/10K per 13" reel (8 mm tape), 10K/bo. 08/3K per 7" reel (8 mm tape), 15K/box

FE/	ATU	RES

- Silicon epitaxial planar diode
- Fast switching dual diode with common cathode
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade
- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ROHS COMPLIANT

ptions:			
mm tape), 10K/box			
m tape), 15K/box			
ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMAR

PARTS TABLE						
PART	ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMARKS		
BAV23C	BAV23C-E3-08 or BAV23C-E3-18	Common cathode	KT6	Tapo and rool		
BAV23C	BAV23C-HE3-08 or BAV23C-HE3-18	Common Cathode	KIU	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Continuous reverse voltage		V _R	200	V	
Repetitive peak reverse voltage		V _{RRM}	250	V	
Non-repetitive peak forward current	t = 1 µs	I _{FSM}	9	A	
Non-repetitive peak forward surge current	t = 1 s	I _{FSM}	0.5	A	
Maximum average forward rectified current (1)		I _{F(AV)}	200	mA	
Forward continuous current ⁽²⁾		I _F	400	mA	
Repetitive peak forward current		I _{FRM}	625	mA	
Power dissipation ⁽²⁾		P _{tot}	350	mW	

Notes

⁽¹⁾ Measured under pulse conditions; pulse time = $t_p \le 0.3$ ms

⁽²⁾ Device on fiberglass substrate

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air ⁽¹⁾		R _{thJA}	357	K/W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-65 to +150	°C	
Operating temperature range		T _{op}	-55 to +150	°C	

Note

⁽¹⁾ Device on fiberglass substrate

Rev. 1.5, 13-Feb-18

1

Document Number: 81902

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u> www.vishay.com

BAV23C

Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	$I_R = 100 \ \mu A, t_p = 300 \ ms$	V _(BR)	250			V
Forward voltage	I _F = 100 mA	V _F			1	V
	I _F = 200 mA	V _F			1.25	V
Reverse current	V _R = 200 V	I _R			100	nA
	$V_R = 200 \text{ V}, \text{ T}_j = 150 ^\circ\text{C}$	I _R			100	μA
Dynamic forward resistance	I _F = 10 mA	r _f		5		Ω
Diode capacitance	$V_R = 0 V$, f = 1 MHz	CD			5	pF
Reverse recovery time	$I_{F} = I_{R} = 30 \text{ mA}, R_{L} = 100 \Omega$ $i_{R} = 3 \text{ mA}$	t _{rr}			50	ns

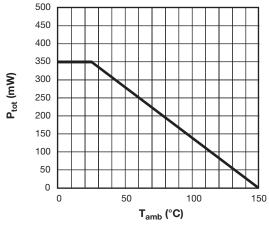


Fig. 1 - P_{tot} - Admissible Power Dissipation vs. Ambient Temperature

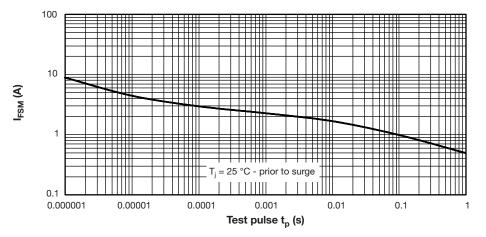


Fig. 2 - I_{FSM} - Non-Repetitive Peak Forward Current vs. Pulse Duration - Maximum Admissible Values of Square Pulses

 Rev. 1.5, 13-Feb-18
 2
 Document Number: 81902

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

BAV23C Vishay Semiconductors



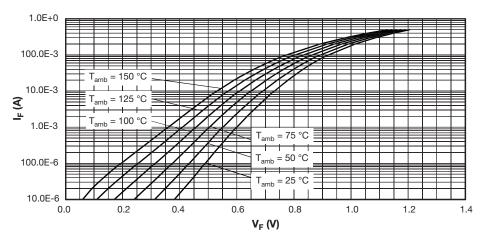


Fig. 3 - V_F - Typical Forward Current vs. Forward Voltage vs. Various Temperatures

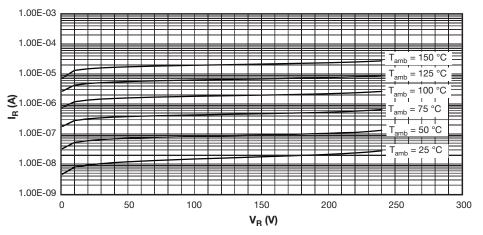
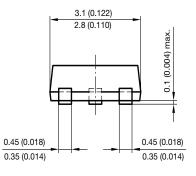


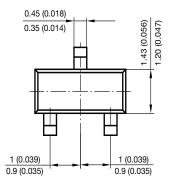
Fig. 4 - I_R - Typical Reverse Current vs. Reverse Voltage vs. Various Temperatures



Vishay Semiconductors

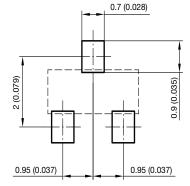
PACKAGE DIMENSIONS in millimeters (inches): SOT-23





0.550 ref. (0.022 ref.) 1.15 (0.045) 0.9 (0.035) 0.175 (0.007) 0.098 (0.004) 0.2 (0.008) å 0° to e 0.5 (0.020) 0.3 (0.012) 2.6 (0.102) 2.35 (0.093)

Foot print recommendation:



Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009 17418

Rev. 1.5, 13-Feb-18 Document Number: 81902 4 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.